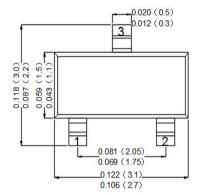


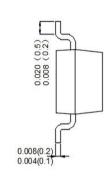


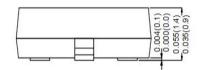
#### **Features**

• General Purpose Amplifier Applications

### **SOT-23**







Dimensions in inches and (millimeters)

## **Mechanical Data**

- Case:Molded Plastic,SOT-23
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable perMIL-STD-750,Method-2026.
- Marking: 2GM
- Mounting Position : Any.
- Equivalent Circuit:

# Maximum Ratings Maximum Ratings (Rating at 25°C ambient temperature unless otherwise specified.)

	Symbol	Value	Unit
Collector Base Voltage	-V <sub>CBO</sub>	80	V
Collector Emitter Voltage	-V <sub>CEO</sub>	80	V
Emitter Base Voltage	-V <sub>EBO</sub>	4	V
Collector Current	-I <sub>C</sub>	500	mA
Total Device Dissipation Derate above 25°C	P <sub>tot</sub>	200 2.8	mW mW/°C
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	357	°C/W
Junction Temperature	T <sub>j</sub>	-55 to +150	°C
Storage Temperature Range	T <sub>S</sub>	-55 to +150	°C

version:00 1 of 4





## **PNP General Purpose Transistor**

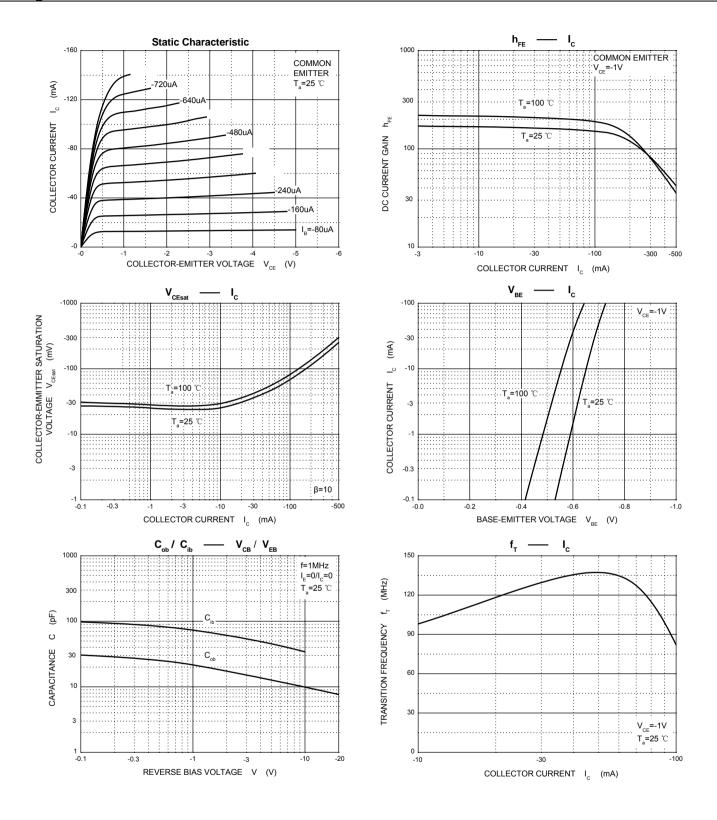
# Electrical Characteristics (Rating at 25°C ambient temperature unless otherwise specified.)

	Symbol	Min.	Max.	Unit
DC Current Gain				
at -I <sub>C</sub> =10mA, -V <sub>CE</sub> =1V	h <sub>FE</sub>	100	400	-
at -I <sub>C</sub> =100mA, -V <sub>CE</sub> =1V	h <sub>FE</sub>	100	-	-
Collector Cutoff Current				
at -V <sub>CB</sub> =80V	-I <sub>CBO</sub>	-	0.1	μΑ
Collector Cutoff Current				
at -V <sub>CE</sub> =60V	-I <sub>CEO</sub>	-	0.1	μΑ
Collector Emitter Breakdown Voltage				
at -I <sub>C</sub> =1mA	-V <sub>(BR)CEO</sub>	80	-	V
Collector Base Breakdown Voltage				
at -I <sub>C</sub> =100μA	-V <sub>(BR)CBO</sub>	80	-	V
Emitter Base Breakdown Voltage				
at -I <sub>E</sub> =100μA	-V <sub>(BR)EBO</sub>	4	-	V
Collector Emitter Saturation Voltage				
at -I <sub>C</sub> =100mA, -I <sub>B</sub> =10mA	-V <sub>CE(sat)</sub>	-	0.25	V
Base Emitter On Voltage				
at -I <sub>C</sub> =100mA, -V <sub>CE</sub> =1V	-V <sub>BE(on)</sub>	-	1.2	V
Current Gain – Bandwidth Product				
at -I <sub>C</sub> =100mA, -V <sub>CE</sub> =1V, f=100MHz	f <sub>T</sub>	50	-	MHz

version:00 2 of 4



## **Rating And Characteristic Curves**



version:00 3 of 4



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version:00 4 of 4